

Product Summary

BV_{DSS}	R_{DS(ON)} Max	I_D T_C = +25°C
600V	3.5Ω @ V _{GS} = 10V	2.8A

Description

This new generation complementary MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

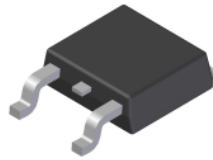
Features

- Low Input Capacitance
- High BV_{DSS} Rating for Power Application
- Low Input/Output Leakage
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

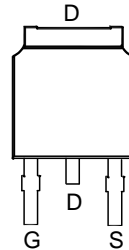
Mechanical Data

- Case: TO252 (DPAK) (Type TH)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 [Ⓔ]
- Weight: 0.33 grams (Approximate)

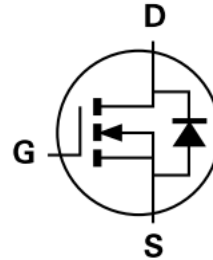
TO252 (DPAK) (Type TH)



Top View



Top View



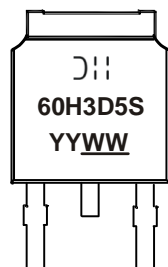
Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN60H3D5SK3-13	TO252 (DPAK) (Type TH)	2,500/Tape & Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



= Manufacturer's Marking
 60H3D5S = Product Type Marking Code
 YYWW = Date Code Marking
 YY or YY = Last Two Digits of Year (ex: 17 = 2017)
 WW or WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	600	V
Gate-Source Voltage			V _{GSS}	±30	V
Continuous Drain Current (Note 5) V _{GS} = 10V	Steady State	T _C = +25°C	I _D	2.8	A
		T _C = +100°C		1.8	
Maximum Body Diode Forward Current (Note 5)			I _S	2.5	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	4.4	A
Avalanche Current, L = 60mH (Note 7)			I _{AS}	1.0	A
Avalanche Energy, L = 60mH (Note 7)			E _{AS}	30	mJ
Peak Diode Recovery dv/dt (V _{DD} = 400V, I _D = 2.7A)			dv/dt	2.7	V/ns

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _C = +25°C	P _D	41	W
	T _C = +100°C		16	
Thermal Resistance, Junction to Ambient (Note 6)		R _{θJA}	46	°C/W
Thermal Resistance, Junction to Case (Note 5)		R _{θJC}	3.0	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	600	—	—	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	1.0	μA	V _{DS} = 600V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±30V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	2.0	3.1	4.0	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	2.7	3.5	Ω	V _{GS} = 10V, I _D = 1.5A
Diode Forward Voltage	V _{SD}	—	0.9	1.5	V	V _{GS} = 0V, I _S = 3.0A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C _{ISS}	—	354	—	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{OSS}	—	41	—		
Reverse Transfer Capacitance	C _{RSS}	—	4	—		
Gate Resistance	R _G	—	2.6	—	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz
Total Gate Charge (V _{GS} = 10V)	Q _g	—	12.6	—	nC	V _{DS} = 480V, I _D = 2.5A
Gate-Source Charge	Q _{gs}	—	1.7	—		
Gate-Drain Charge	Q _{gd}	—	7.1	—		
Turn-On Delay Time	t _{D(ON)}	—	10.6	—	ns	V _{GS} = 10V, V _{DD} = 300V, R _G = 25Ω, I _D = 2.5A
Turn-On Rise Time	t _r	—	22	—		
Turn-Off Delay Time	t _{D(OFF)}	—	34	—		
Turn-Off Fall Time	t _f	—	28	—		
Body Diode Reverse Recovery Time	t _{RR}	—	198	—	ns	V _{GS} = 0V, I _S = 2.5A, di/dt = 100A/μs
Body Diode Reverse Recovery Charge	Q _{RR}	—	952	—	nC	

- Notes:
- Device mounted on infinite heatsink.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
 - Guaranteed by design. Not subject to production testing.
 - Short duration pulse test used to minimize self-heating effect.

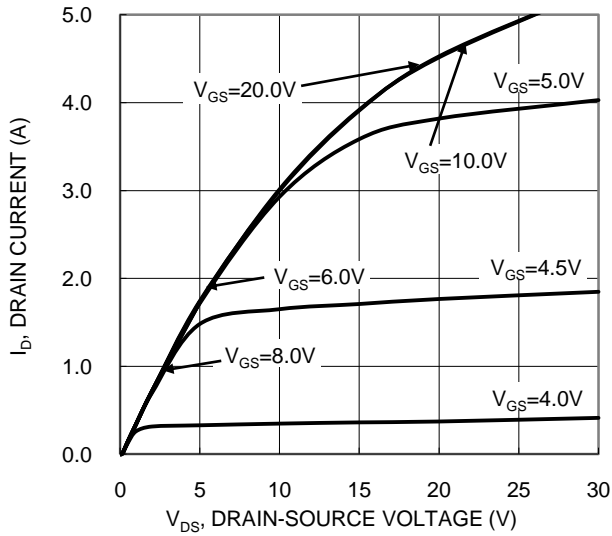


Figure 1. Typical Output Characteristic

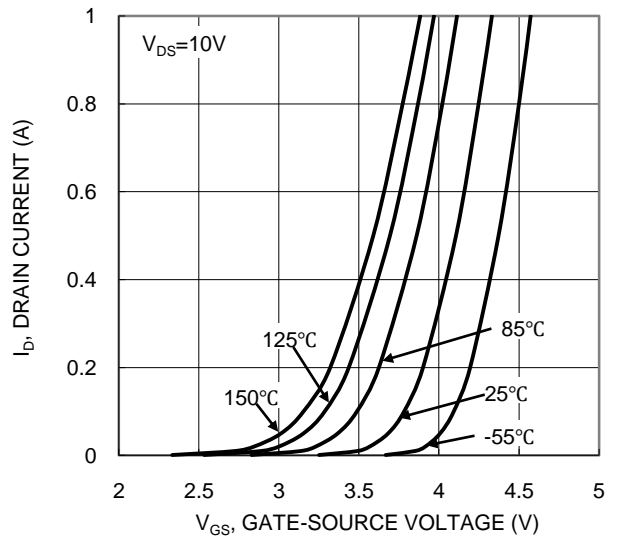


Figure 2. Typical Transfer Characteristic

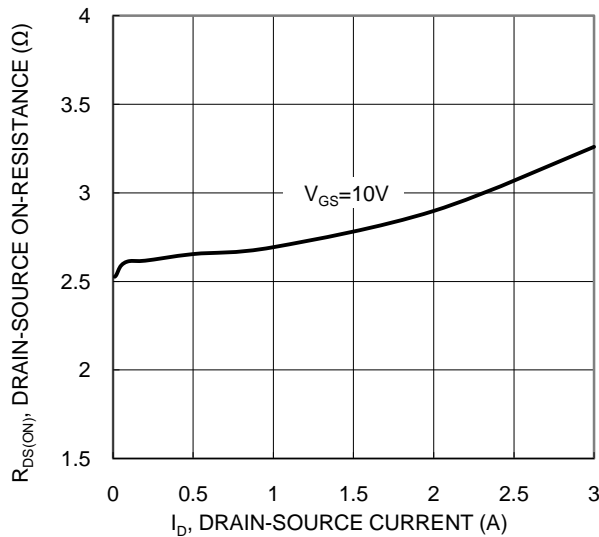


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

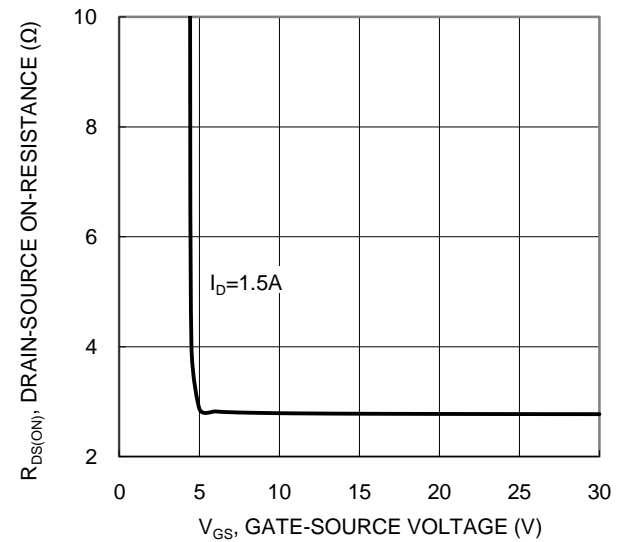


Figure 4. Typical Transfer Characteristic

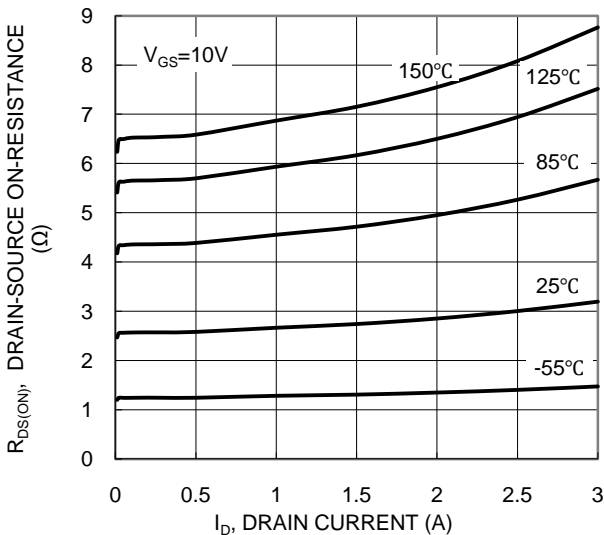


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

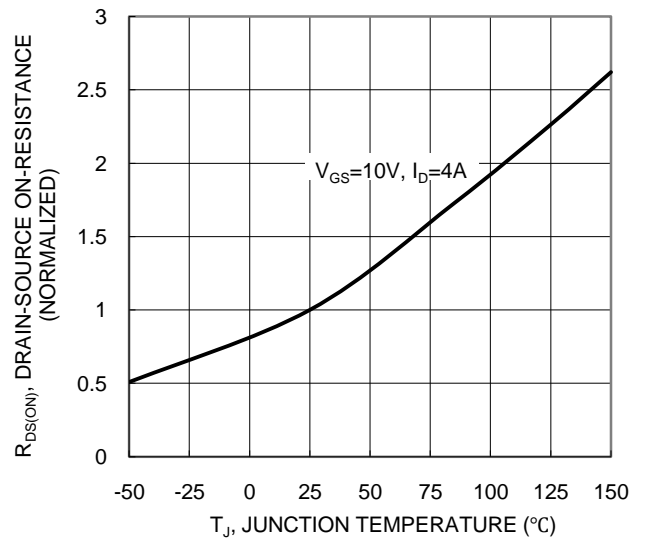


Figure 6. On-Resistance Variation with Temperature

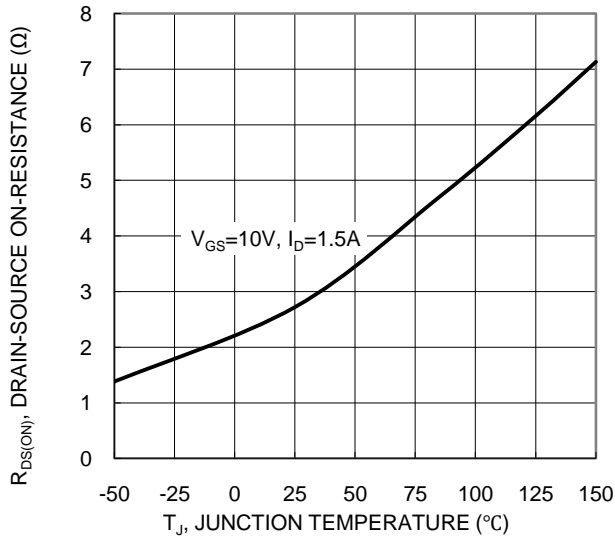


Figure 7. On-Resistance Variation with Temperature

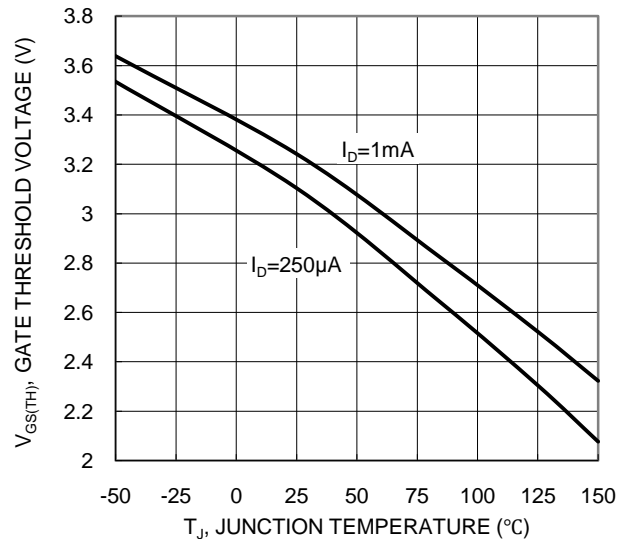


Figure 8. Gate Threshold Variation vs. Temperature

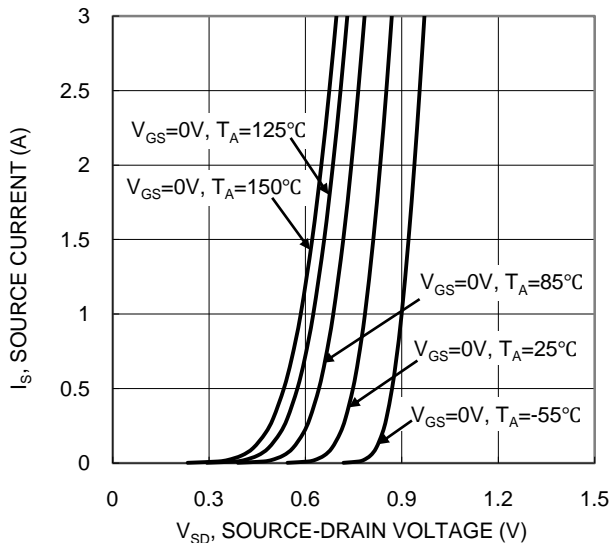


Figure 9. Diode Forward Voltage vs. Current

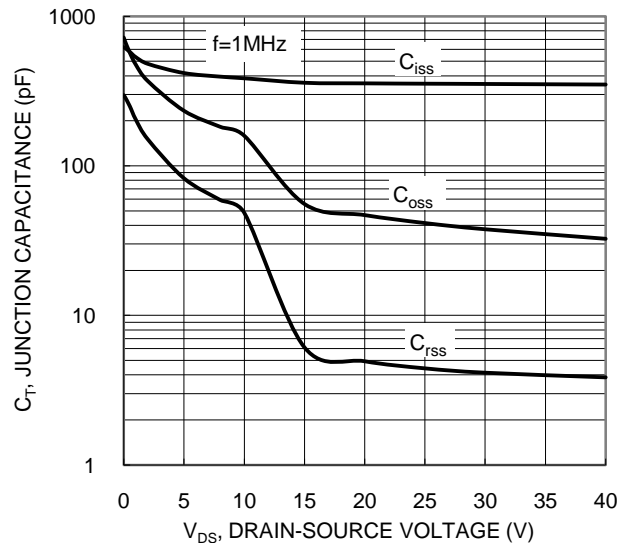


Figure 10. Typical Junction Capacitance

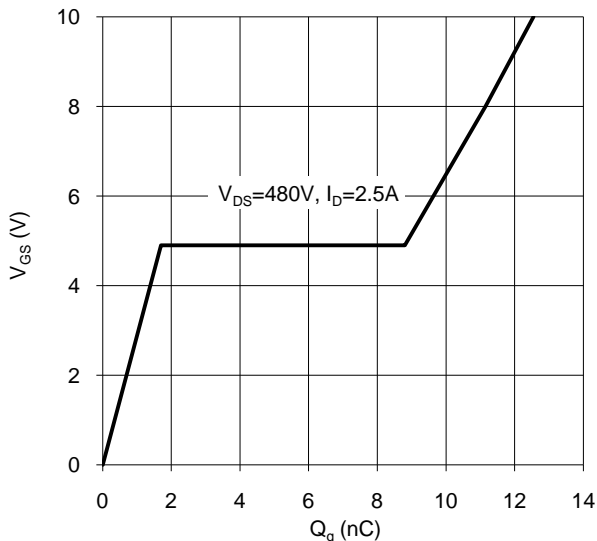


Figure 11. Gate Charge

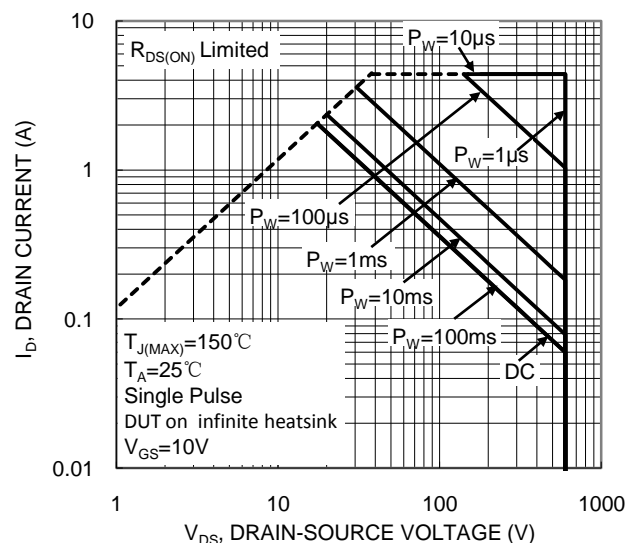


Figure 12. SOA, Safe Operation Area

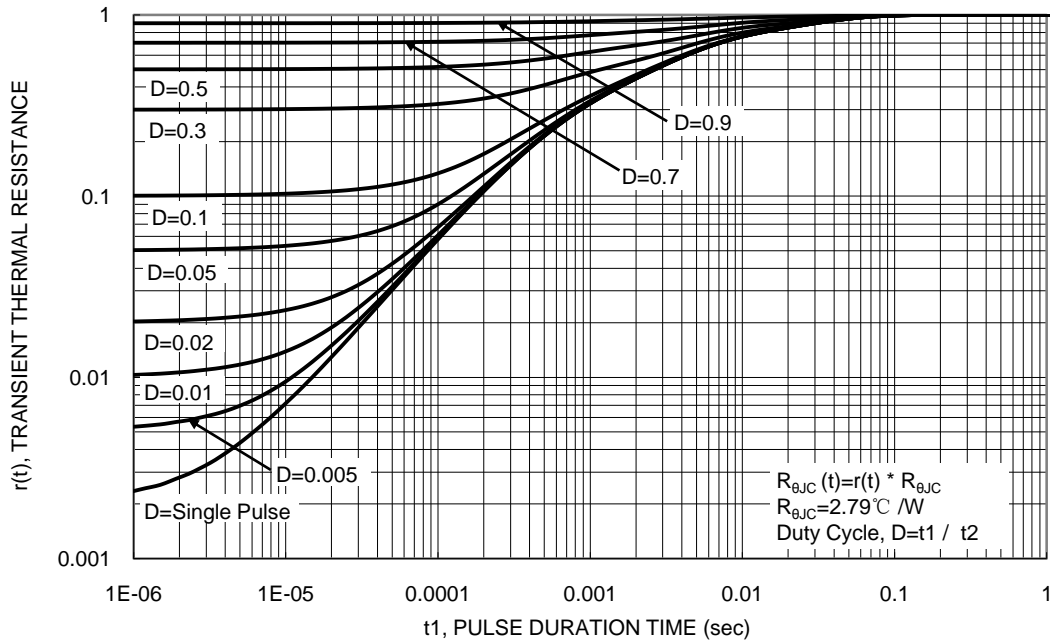
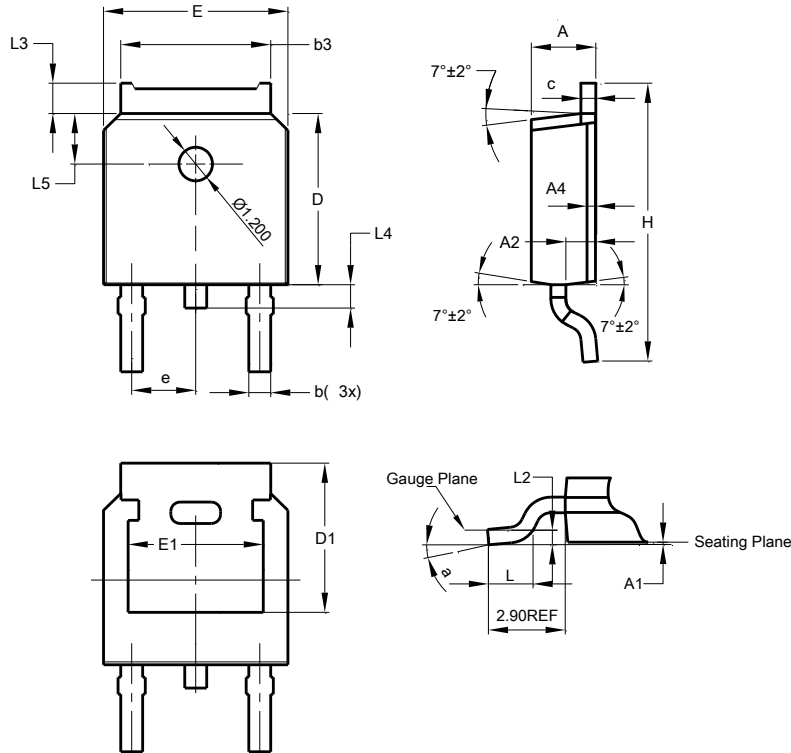


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK) (Type TH)

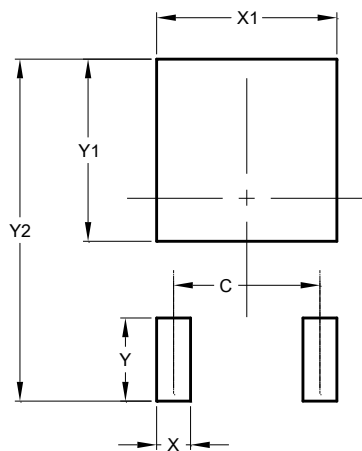


TO252 (DPAK) (Type TH)			
Dim	Min	Max	Typ
A	2.20	2.38	2.30
A1	0.00	0.10	-
A2	0.97	1.17	1.07
A4	0.10 REF		
b	0.72	0.85	0.78
b3	5.23	5.45	5.33
c	0.47	0.58	0.53
D	6.00	6.20	6.10
D1	5.30 REF		
e	2.286 BSC		
E	6.50	6.70	6.60
E1	4.70	4.92	4.83
H	9.90	10.10	10.30
L	1.40	1.70	1.60
L2	0.51 BSC		
L3	0.90	1.25	-
L4	0.60	1.00	0.80
L5	1.70	1.90	1.80
a	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK) (Type TH)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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